

# **OBSOLETE**

**Data Sheet** 

#### **Single Phase Synchronous Buck PWM Controller**

AP3581A/B/C

#### **General Description**

The AP3581A/B/C is a compact synchronous-rect ified buck controller specifically designed to operate from 5V/12V supply and deliver high-quality output voltage as low as 0.6V (AP3581A) or 0.8V (AP3581B/C). The AP3581A/B/C operates at fixed frequency of 300kHz (AP3581A/B) or 200kHz (AP3581C) and provides an optimal level of integration to reduce size and cost of the power supply.

This controller integrates internal MOSFET drivers that support 12V+12V bootstrapped voltage for highefficiency power conversion. The bootstrap diode is built-in to simplify the circuit design and minimize external part count.

This controller provides single feedback loop, voltage-mode control with fast transient response. The error amplifier features a 10MHz gain-bandwidth product and  $6V/\mu s$  slew rate which enables high converter bandwidth for fast transient performance.

Other features include internal soft-start, under voltage protection, over current protection and shutdown function. With afore-mentioned functions, this part provides customers a compact, high efficiency, well-protected and cost-effective solutions.

The AP3581A/B/C is available in PSOP-8 package.

#### **Features**

- Supply Voltage: 5V/12V
   V<sub>IN</sub> Input Range: 3.0V to 13.2V
   0.6V/0.8V to 80% of V<sub>IN</sub> Output Range Internal Reference: 0.6V/0.8V
- Simple Single-loop Control Voltage-mode PWM Control Duty Cycle: 0% to 80% Fast Transient Response
- 10MHz High-bandwidth Error Amplifier with 6V/µs Slew Rate
- Fixed Oscillator Frequency: 300kHz/200kHz
- Lossless, Programmable Over Current Protection (Uses Lower MOSFET R<sub>DS(ON)</sub>)
- Start-up into Pre-biased Output
- · Built-in Thermal Shutdown
- Built-in Soft-start
- Over Current/Voltage Protection
- Under Voltage Protection
- Integrated Boot Diode

#### **Applications**

- Power Supplies for Microprocessors/Peripherals PCs, Embedded Controllers, Memory Supplies DSP and Core Communications Processor Supplies
- Subsystem Power Supplies
   PCI, AGP, Graphics Cards, Digital TV
   SSTL-2 and DDR/2/3 SDRAM Bus Termination
   Supply
- Cable Modems, Set Top Boxes, and DSL Modems
- Industrial Power Supplies and General Purpose Supplies
- 5V/12V Input DC-DC Regulators
- Low-voltage Distributed Power Supplies

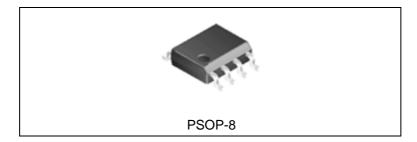


Figure 1. Package Type of AP3581A/B/C



AP3581A/B/C

# **Pin Configuration**

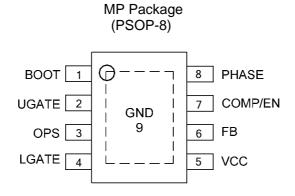


Figure 2. Pin Configuration of AP3581A/B/C (Top View)

## **Pin Description**

Pin Number	Pin Name	Function				
1	ВООТ	Bootstrap pin. Connect a bootstrap capacitor (Typically from $0.1\mu F$ to $0.47\mu F$ ) from this pin to PHASE pin to create a BOOT voltage suitable to drive a standard N-Channel MOSFET				
2	UGATE	Upper-gate drive pin. Connect this pin to the upper MOSFET gate providing the gate drive. This pin is monitored by the adaptive shoot-through protection circuitry to determine when the upper MOSFET has been turned off				
3	OPS	Over-current setting pin. Connecting a resistor ( $R_{OCSET}$ ) between OPS and GND to set the over-current trigger point				
4	LGATE	Lower-gate drive pin. Connect LGATE to the lower MOSFET gate providing the gate drive for the lower MOSFET. This pin is monitored by the adaptive shoot-through protection circuitry to determine when the lower MOSFET has turned off				
5	VCC	Bias supply pin. Provides a 5V or 12V bias supply for the chip from this pin. The pin should be bypassed with a capacitor to GND				
6	FB	Feedback pin. This pin is the inverting input of the internal error amplifier. Use FB pin, in combination with the COMP pin, to compensate the voltage control feedback loop of the converter. A resistor divider from output to GND is used to set the output voltage				
7	COMP/EN	Compensation and disable pin, this pin is the output of the error amplifier. Pull COMP pin low will shut down the IC				
8	PHASE	PHASE pin. This pin connects to the source of the upper MOSFET and the drain of the lower MOSFET. This pin is also monitored by the adaptive shoot-through protection circuitry to determine when the upper MOSFET has turned off				
9	GND	Exposed pad as ground pin. Represents the signal and power ground for the IC. Tie this pin to the ground island/plane through the lowest impedance connection available				



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### **Functional Block Diagram**

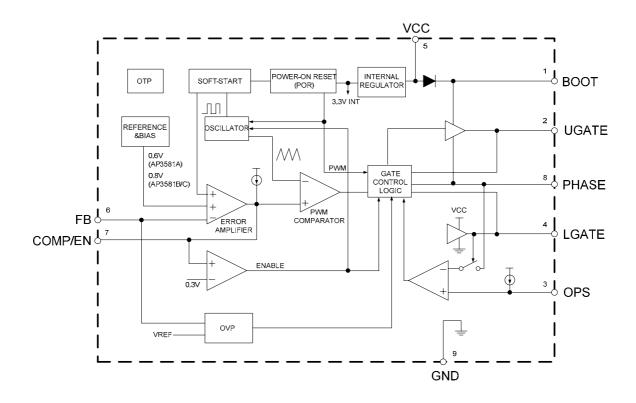
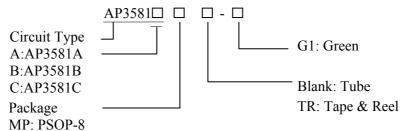


Figure 3. Functional Block Diagram of AP3581A/B/C

### **Ordering Information**



Package	Temperature Range	Part Number	Marking ID	Packing Type	
PSOP-8	-40 to 85°C	AP3581AMP-G1	3581AMP-G1	Tube	
		AP3581AMPTR-G1	3581AMP-G1	Tape & Reel	
		AP3581BMP-G1	3581BMP-G1	Tube	
		AP3581BMPTR-G1	3581BMP-G1	Tape & Reel	
		AP3581CMP-G1	3581CMP-G1	Tube	
		AP3581CMPTR-G1	3581CMP-G1	Tape & Reel	

BCD Semiconductor's Pb-free products, as designated with "G1" suffix in the part number, are RoHS compliant and green.



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#### **Absolute Maximum Ratings (Note 1)**

Parameter	Symbol	Value	Unit
Supply Voltage	V <sub>CC</sub>	-0.3 to 15	V
BOOT Voltage	$V_{BOOT}$	-0.3 to V <sub>PHASE</sub> +15	V
Voltage from UGATE to PHASE	$V_{UGATE}$	-0.3 to 15	V
Voltage from PHASE, LGATE Pin to GND	$V_{ m PHASE}, \ V_{ m LGATE}$	-1 to 15	V
Voltage on Other Separate Pin		-0.3 to 6	V
Thermal Resistance	$\theta_{\mathrm{JA}}$	50	°C/W
Operating Junction Temperature	$T_{\mathrm{J}}$	-40 to 125	°C
Storage Temperature	$T_{STG}$	-65 to 150	°C
Lead Temperature (Soldering, 10 sec)	$T_{LEAD}$	260	°C
ESD (Human Body Model) (Note 2)		2000	V
ESD (Machine Model) (Note 2)		200	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Note 2: Devices are ESD sensitive. Handling precaution recommended.

### **Recommended Operating Conditions**

Parameter	Symbol	Min	Max	Unit
Supply Input Voltage	$V_{CC}$	4.5	13.2	V
Operating Junction Temperature Range	$T_{J}$	-40	125	°C
Operating Ambient Temperature	$T_{A}$	-40	85	°C



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## **Electrical Characteristics**

 $V_{CC}$ =12V,  $T_A$ =25°C, unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
SUPPLY INPUT						
Supply Voltage	V <sub>CC</sub>		4.5		13.2	V
Supply Current	$I_{CC}$	UGATE and LGATE Pin Open; V <sub>CC</sub> =12V, Switching		5		mA
Quiescent Supply Current	$I_{CC_Q}$	V <sub>FB</sub> =V <sub>REF</sub> +0.1V, No Switching		4		mA
Power Input Voltage	$V_{IN}$		3.0		13.2	V
POWER ON RESET						
V <sub>CC</sub> Rising Threshold	$V_{POR}$	V <sub>CC</sub> Rising	4.0	4.2	4.4	V
V <sub>CC</sub> Threshold Hysteresis	$V_{POR\_HYS}$			500		mV
OSCILLATOR		1		l		
O Illator Francisco	_	AP3581A/B	270	300	330	
Oscillator Frequency	$f_{OSC}$	AP3581C	180	200	220	kHz
Ramp Amplitude	$\Delta V_{OSC}$	V <sub>CC</sub> =12V		1.8		V
ERROR AMPLIFIER		1		l		
Open Loop DC Gain (Note 3)	$G_{DC\_OL}$		55	70		dB
Gain Bandwidth (Note 3)	$G_{\mathrm{BW}}$			10		MHz
Slew Rate (Note 3)	SR		3	6		V/µs
Transconductance				800	1100	μA/V
Output Source Current		$V_{FB} < V_{REF}$	80	120		μΑ
Output Sink Current		$V_{FB} > V_{REF}$	80	120		μΑ
PWM CONTROLLER GATE DRIVER	RS					
Upper Gate Source Current	$I_{UG\_SRC}$	$V_{BOOT}$ - $V_{PHASE}$ =12V, $V_{BOOT}$ - $V_{UGATE}$ =6V		-1		A
Upper Gate Sink Current	$I_{UG\_SNK}$	V <sub>BOOT</sub> -V <sub>PHASE</sub> =12V, V <sub>BOOT</sub> -V <sub>UGATE</sub> =6V		1.5		A
Upper Gate Sink Resistance	$R_{\text{UGATE}}$	50mA Sink Current, V <sub>BOOT</sub> -V <sub>PHASE</sub> =12V		1.6	3.2	Ω
Lower Gate Source Current	$I_{LG\_SRC}$	V <sub>CC</sub> -V <sub>LGATE</sub> =6V		-1		A
Lower Gate Sink Current	$I_{LG\_SNK}$	V <sub>LGATE</sub> =6V		1.5		A
Lower Gate Sink Resistance	R <sub>LGATE</sub>	50mA Sink Current, V <sub>CC</sub> =12V		1	2	Ω
PHASE Falling to LGATE Rising Delay		$V_{PHASE}$ <1.2V to $V_{LGATE}$ >1.2V		50		ns



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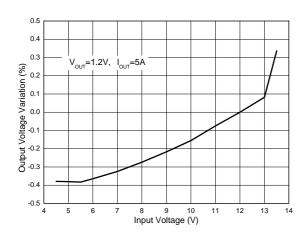
### **Electrical Characteristics (Continued)**

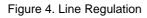
 $V_{CC}$ =12V,  $T_A$ =25°C, unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
LGATE Falling to UGATE Rising Delay		$V_{LGATE}$ <1.2V to $(V_{UGATE}$ - $V_{PHASE}$ )>1.2V		50		ns
Minimum Duty Cycle				0		%
Maximum Duty Cycle			75	80	85	%
REFERENCE VOLTAGE				•		
Foodback Voltage	$ m V_{FB}$	AP3581A	0.591	0.6	0.609	V
Feedback Voltage		AP3581B/C	0.788	0.8	0.812	V
PROTECTION						
Under Voltage Protection	$V_{FB\_UVP}$		0.3	0.4	0.5	V
Over Current Source	$I_{OPS}$		30	40	50	μΑ
	$t_{\rm SS}$	AP3581A		2.0		
Soft-start Interval		AP3581B		2.7		ms
		AP3581C		3.6		
Enable Threshold	V <sub>COMP/EN</sub>		0.25	0.30	0.35	V
Thermal Shutdown	$T_{OTSD}$			160		°C
Thermal Shutdown Hysteresis	$T_{HYS}$			20		°C

Note 3: Not tested, guaranteed by design.

## **Typical Performance Characteristics**





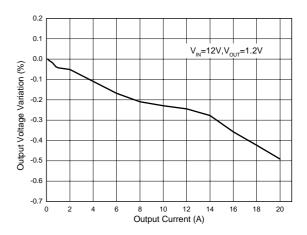
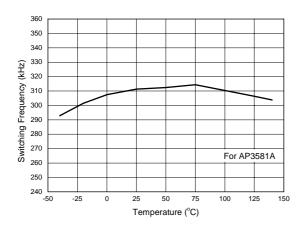


Figure 5. Load Regulation



## AP3581A/B/C



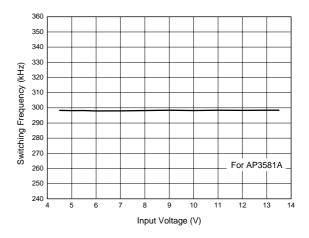
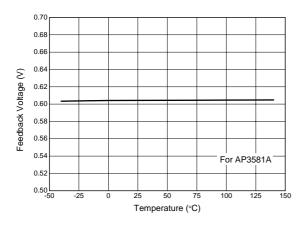
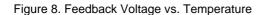


Figure 6. Switching Frequency vs. Temperature

Figure 7. Switching Frequency vs. Input Voltage





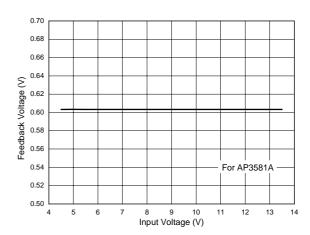


Figure 9. Feedback Voltage vs. Input Voltage



AP3581A/B/C

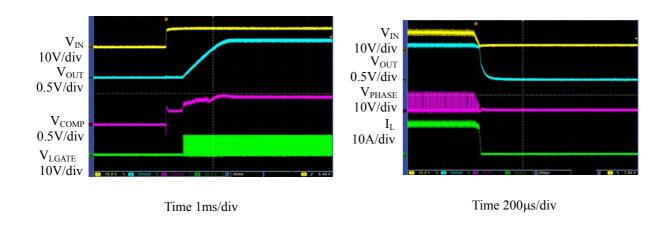


Figure 10. Power-on Waveform  $(V_{IN}=12V, V_{OUT}=1.2V, I_{OUT}=0A)$ 

Figure 11. Power-off Waveform ( $V_{IN}$ =12V,  $V_{OUT}$ =1.2V,  $I_{OUT}$ =20A)

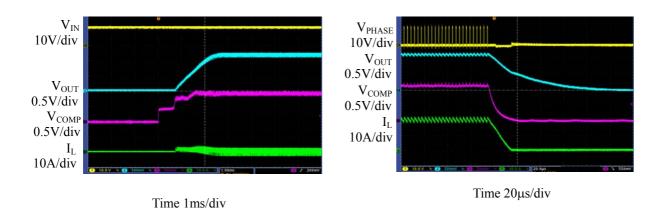


Figure 12. Enable Waveform (V<sub>IN</sub>=12V, V<sub>OUT</sub>=1.2V, I<sub>OUT</sub>=0A)

Figure 13. Disable Waveform (V<sub>IN</sub>=12V, V<sub>OUT</sub>=1.2V, I<sub>OUT</sub>=20A)



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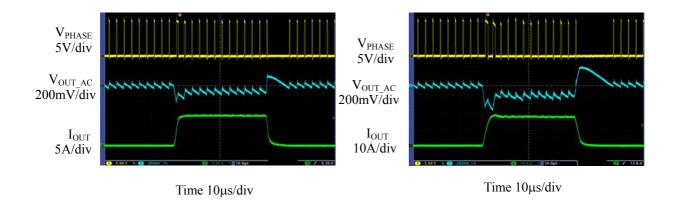


Figure 14. Load Transient Response  $(V_{IN}=12V, V_{OUT}=1.2V, I_{OUT}=0A \text{ to } 10A)$ 

Figure 15. Load Transient Response (V<sub>IN</sub>=12V, V<sub>OUT</sub>=1.2V, I<sub>OUT</sub>=0A to 20A)

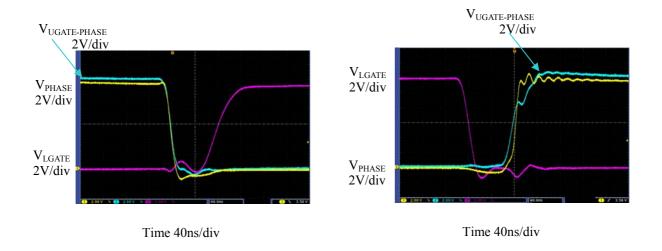
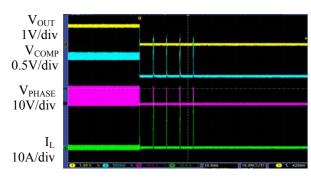


Figure 16. UGATE Turn Off Waveforms  $(V_{CC}=V_{IN}=12V, V_{OUT}=1.2V, I_{OUT}=20A)$ 

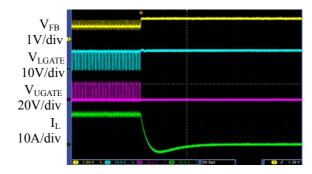
Figure 17. UGATE Turn On Waveforms  $(V_{CC}=V_{IN}=12V, V_{OUT}=1.2V, I_{OUT}=20A)$ 



### AP3581A/B/C



Time 10ms/div



Time 80µs/div

Figure 18. Over Current Protection  $(V_{IN}=12V, V_{OUT}=1.2V \text{ to } 0V, I_{OUT}=0A)$ 

Figure 19. Over Voltage Protection  $(V_{IN}=12V, V_{OUT}=1.2V, I_{OUT}=20A)$ 



AP3581A/B/C

# **Typical Application**

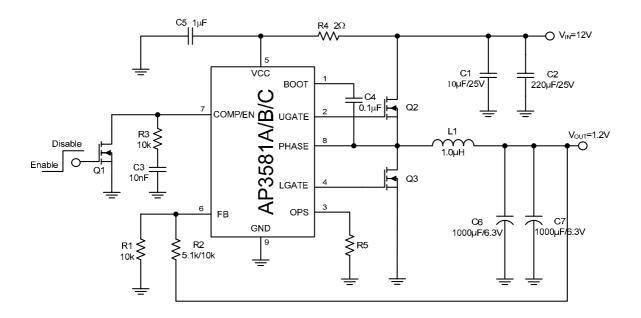


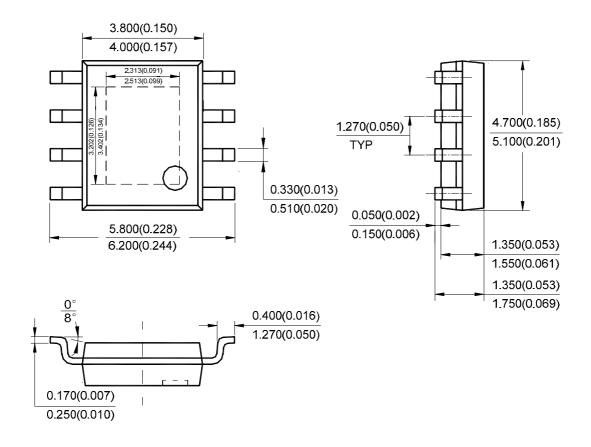
Figure 20. Typical Application Circuit of AP3581A/B/C



AP3581A/B/C

#### **Mechanical Dimensions**

PSOP-8 Unit: mm(inch)



Note: Eject hole, oriented hole and mold mark is optional.





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